

OFFSET CONTROL CIRCUIT

BACKGROUND OF THE INVENTION

The present invention relates to offset control circuits for adjusting an output
5 voltage so as to correspond to an input voltage.

Conventionally, an offset control circuit as shown in Fig. 16 is used for adjusting the amount of offset contained in the input and output of an operational amplifier, for example.

In Fig. 16, an offset control circuit 200 is configured by connecting the output
10 terminal of an operational amplifier 201 (op-amp) in series with resistors R1 and R2, as well as a variable voltage generating source 202, and connecting the point where the resistors R1 and R2 are connected to the negative input terminal of the operational amplifier 201. An input voltage VIN+ is input to the positive input terminal of the operational amplifier 201, and an output voltage VO is output from the output terminal of the operational amplifier 201.

15 Here, in order to apply an offset voltage to the input voltage VIN of the operational amplifier 201 and generate the output voltage VO, an output voltage V2 from the variable voltage generating source 202 is freely changeable. Due to the characteristics of the operational amplifier 201, an input voltage V1 (VIN-) applied to the negative input terminal of this operational amplifier 201 is the same as the input voltage VIN+ to the positive input
20 terminal. The output voltage signal VO from the operational amplifier 201 is determined by the resistors R1 and R2, the input voltage VIN+ and the output voltage V2. For this reason, the output voltage VO can be output from the operational amplifier 201 while adjusting its offset with respect to the input voltage VIN by adjusting the output voltage V2 with the variable voltage generating source 202.

25 The above-described conventional offset control circuit 200, however, is not suited to high-speed operations, because it uses the operational amplifier 201, which operates at low speed. Moreover, the operational amplifier 201 in general cannot operate normally

without having a band that is 10 to 100 times the signal band used, so that it is necessary to use powerful transistors, and it is necessary to use even more powerful transistors, in order to configure the operational amplifier 201 so as to be capable of operating at high speeds. This results in the problem of significantly increased power consumption and an increased 5 scale of the circuit.

Further, the above-described conventional offset control circuit 200 is configured such that a single input voltage **VIN+** is input to the operational amplifier 201. Therefore, if the input voltage signal **VIN+** contains any undesirable components such as noise components, the distortion characteristics of the signal voltage deteriorate, reducing the 10 quality of the output voltage **VO**.

In order to prevent such deterioration of the distortion characteristics, it is conceivable to input a pair of differential input voltages to the offset control circuit to generate a differential output voltage proportional to the voltage difference between the two input voltages, and use this for the offset adjustment. When a highly accurate analog 15 signal processing is actually performed, it is necessary to carry out the offset adjustment with the differential output voltage in order to prevent the deterioration of the distortion characteristics of the signal voltage.

However, in order to carry out the offset adjustment with the differential output voltage by using the above-described conventional offset control circuit 200, it is necessary 20 to use two offset control circuits 200, resulting in the problem of an increased scale of the circuit.

SUMMARY OF THE INVENTION

Therefore, with the foregoing in mind, it is an object of the present invention to 25 provide an offset control circuit that can be reduced in size without increasing the scale of the circuit, operate at high speeds and prevent the deterioration of the distortion characteristics of signals.

In order to achieve the above-described object, according to the present invention, a differential input voltage is converted into a current, followed by adding an offset adjusting current to this differential current, and the differential current to which this offset adjusting current has been added is converted to a voltage, thereby providing an offset control circuit 5 that can operate at high speeds and can reduce the distortion characteristics of signals without using any operational amplifier.

More specifically, the present invention provides an offset control circuit for adjusting offset voltages contained in differential voltages that are input from a pair of differential voltage input terminals and outputting the adjusted differential voltages from a 10 pair of differential voltage output terminals, the offset control circuit comprising: a voltage/current converting portion that includes the pair of differential voltage input terminals and a pair of differential current output terminals, that generates a pair of differential output currents corresponding to a potential difference between a pair of differential input voltages input from the pair of differential voltage input terminals, and that 15 outputs the pair of differential output currents from the pair of differential current output terminals; an offset adjusting current-generating portion that includes a pair of offset adjusting current-output terminals connected to the pair of differential current output terminals of the voltage/current converting portion, and at least two offset adjusting current-control terminals, that generates a pair of offset adjusting currents by being controlled by 20 offset adjusting current control signals input from the offset adjusting current-control terminals, and that outputs the pair of offset adjusting currents from the pair of offset adjusting current-output terminals; and a current/voltage converting portion that includes a pair of differential terminals connected to the pair of differential current output terminals of the voltage/current converting portion, the pair of offset adjusting current-output terminals 25 of the offset adjusting current-generating portion and the pair of differential voltage output terminals, that feeds a current flowing between the two differential terminals constituting the pair of differential terminals, that converts the current into a corresponding voltage, and that

generates the converted voltage at the pair of differential voltage output terminals.

Preferably, in the above-described offset control circuit of the present invention, the voltage/current converting portion includes: a pair of bias current sources connected to the pair of differential current output terminals; a pair of first transistors whose first driving terminals are connected to the pair of differential current output terminals, respectively, and whose gates are both connected to a control terminal; and a pair of second transistors whose first driving terminals are connected to second driving terminals of the pair of first transistors, respectively, whose gates are connected to the pair of differential voltage input terminals, respectively, and whose second driving terminals are connected to a reference potential supplying point.

In accordance with another aspect, the present invention also provides an offset control circuit for adjusting offset voltages contained in differential voltages that are input from a pair of differential voltage input terminals and outputting the adjusted differential voltages from a pair of differential voltage output terminals, the offset control circuit comprising: a voltage/current converting portion that includes the pair of differential voltage input terminals, a pair of differential current output terminals connected to the pair of differential voltage output terminals, a pair of bias current sources to which the pair of differential current output terminals are connected, a pair of first transistors whose first driving terminals are connected to the pair of differential current output terminals and whose gates are connected to a pair of control terminals and a pair of second transistors whose first driving terminals are connected to second driving terminals of the pair of first transistors, whose gates are connected to the pair of differential voltage input terminals, respectively, and whose second driving terminals are connected to a reference potential supplying point, that generates a pair of differential output currents corresponding to a potential difference between a pair of differential input voltages input from the pair of differential voltage input terminals, and that outputs the differential output currents from the pair of differential current output terminals; an offset adjusting current-generating portion that includes a pair

of offset adjusting current-output terminals connected to the first driving terminals of the pair of second transistors of the voltage/current converting portion, and at least two offset adjusting current-control terminals, that generates a pair of offset adjusting currents by being controlled by offset adjusting current-control signals input from the offset adjusting current-control terminals, and that outputs the pair of offset adjusting currents from the pair of offset adjusting current-output terminals; and a current/voltage converting portion that includes a pair of differential terminals connected to the pair of differential current output terminals of the voltage/current converting portion, that feeds a current flowing between the two differential terminals constituting the pair of differential terminals, that converts the current into a corresponding voltage, and that generates the converted voltage at the pair of differential voltage output terminals.

Preferably, in the above-described offset control circuit, the voltage/current converting portion includes: a pair of bias current sources to which the pair of differential current output terminals are connected, respectively; a pair of second transistors whose first driving terminals are connected to the pair of differential current output terminals, respectively, and whose gates are connected to the pair of differential voltage input terminals, respectively; a pair of first transistors whose first driving terminals are connected to second driving terminals of the pair of second transistors, respectively, whose gates are both connected to a control terminal and whose second driving terminals are connected to a reference potential supplying point; and resistor means having a predetermined resistance and being connected between the second driving terminals of the pair of second transistors.

Preferably, in the above-described offset control circuit, the voltage/current converting portion includes: a pair of bias current sources to which the pair of differential current output terminals are connected, respectively; and a pair of transistors whose first driving terminals are connected to the pair of differential current output terminals, respectively, whose gates are connected to the pair of differential voltage input terminals, respectively, and whose second driving terminals are connected to a reference potential

supplying point.

Preferably, in the above-described offset control circuit, the current/voltage converting portion is resistor means having a predetermined resistance and being connected between the pair of differential terminals.

5 Preferably, in the above-described offset control circuit, the current/voltage converting portion includes: a pair of third transistors whose first driving terminals are connected to the pair of differential terminals, respectively, and whose gates are both connected to an input/output current control terminal; and a pair of fourth transistors whose first driving terminals are connected to second driving terminals of the pair of third
10 transistors, respectively, whose gates are connected to the pair of differential terminals, respectively, and whose second driving terminals are connected to a reference potential supplying point.

Preferably, in the above-described offset control circuit, the current/voltage converting portion is a fifth transistor that is connected between the pair of differential terminals and whose gate is connected to an input/output current control terminal.
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Preferably, in the above-described offset control circuit, the offset adjusting current-generating portion includes: a current source; and a pair of sixth transistors whose second driving terminals are connected to the current source, whose gates are connected to two of the offset adjusting current-control terminals, respectively, and whose first driving terminals
20 are connected to the pair of offset adjusting current-output terminals, respectively.

Preferably, in the above-described offset control circuit, the offset adjusting current-generating portion includes n (n is a natural number) sub-offset adjusting current-generating portions; wherein the sub-offset adjusting current-generating portions each include an offset adjusting current-control terminal to which a one-bit signal out of an n -bit register signal is
25 input such that the one-bit signals do not overlap with each other; a current source; and a pair of seventh transistors whose second driving terminals are connected to the current source, one of whose gates is connected to the offset adjusting current-control terminal, the

other of whose gates is connected to the offset adjusting current-control terminal via an inverter and whose first driving terminals are connected to the pair of offset adjusting current-output terminals, respectively; and wherein a pair of sub-offset adjusting currents generated in each of the sub-offset adjusting current-generating portions are supplied to the 5 pair of offset adjusting current-output terminals, respectively.

The present invention also provides a signal processing device comprising: the above-described offset control circuit; and a processing circuit that performs predetermined processing for a differential output voltage whose offset voltage has been adjusted with the offset control circuit; wherein the offset control circuit and the processing circuit are formed 10 on a single chip.

Preferably, in the above-described signal processing device, the signal processing device is a part of a DVD reproduction device; wherein the offset control circuit adjusts an offset voltage contained in a signal read out from a DVD and outputs the adjusted signal as a differential output voltage; and wherein the processing circuit includes: a front-end having a 15 filter that performs a filtering process on the differential output voltage whose offset voltage has been adjusted with the offset control circuit; and a back-end that converts an output signal from the front-end into an image signal and an audio signal.

As described above, the present invention has the following functions.

According to the present invention, the differential current output terminals of the 20 voltage/current converting portion from which differential output currents (I_+ and I_-) that are proportional to the potential difference between the differential input voltage signals (V_{IN+} and V_{IN-}) are output, the offset adjusting current-output terminals of the offset adjusting current-generating portion from which the offset adjusting currents (I_{ofs+} and I_{ofs-}) are output, and the differential terminals of the current/voltage converting portion 25 to/from which a differential input/output current (I_r) that is proportional to the potential difference between the differential terminals is input/output are connected. Accordingly, the differential output voltages (VO_+ and VO_-) that are proportional to the total current of

the differential output currents and the offset adjusting currents are output from the differential voltage output terminals connected to the differential terminals. Therefore, when the differential input voltages (V_{IN+} and V_{IN-}) contain the offset voltages (V_{off+} and V_{off-}), it is possible to adjust these offset voltages with the offset adjusting currents (I_{ofs+} and I_{ofs-}) and add the offset adjusting signals corresponding to the offset voltages to the differential input voltages (V_{IN+} and V_{IN-}), thereby generating the differential output voltages (V_{O+} and V_{O-}).

Accordingly, the addition of the offset adjusting voltages to the differential input voltages is performed by a current addition after converting these voltages into the differential output currents (I_+ and I_-) and the offset adjusting currents (I_{ofs+} and I_{ofs-}), so that it is possible to perform the offset voltage adjustment at high speeds.

Moreover, the offset control circuit according to the present invention can reduce the scale of the circuit since it does not require any operational amplifier (op-amp) unlike the conventional offset control circuit. It also has a strong noise resistance and hardly causes signal distortion, because it performs the processing of differential signals.

BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 is a diagram showing the entire configuration of a DVD signal reproduction processing system.

Fig. 2 is a diagram showing the internal configurations of an analog front end and a PRML read channel, each provided with the same DVD signal reproduction processing system.

Fig. 3 is a block diagram showing an example of the configuration of the offset control circuit according to a first embodiment of the present invention.

Fig. 4 is a circuit diagram showing one specific example of the voltage/current converting circuit shown in Fig. 3.

Fig. 5 is a circuit diagram showing an example of the configuration of the offset

control circuit according to a third embodiment of the present invention.

Fig. 6 is a circuit diagram showing another specific example of the voltage/current converting circuit shown in Fig. 3.

Fig. 7 is a circuit diagram showing yet another specific example of the voltage/current converting circuit shown in Fig. 3.

Fig. 8 is a circuit diagram showing one specific example of the current/voltage converting circuit shown in Fig. 3.

Fig. 9 is a circuit diagram showing another specific example of the current/voltage converting circuit shown in Fig. 3.

Fig. 10 is a circuit diagram showing yet another specific example of the current/voltage converting circuit shown in Fig. 3.

Fig. 11 is a circuit diagram showing one specific example of the offset adjusting current-generating circuit shown in Fig. 3.

Fig. 12 is a circuit diagram showing another specific example of the offset adjusting current-generating circuit shown in Fig. 3.

Fig. 13 is a circuit diagram showing an example of the configuration of an offset adjusting current-generating circuit that is different from the offset adjusting current-generating circuit shown in Fig. 3.

Fig. 14 is a circuit diagram showing one specific example of the offset adjusting current-generating circuit shown in Fig. 13.

Fig. 15 is a circuit diagram showing another specific example of the offset adjusting current-generating circuit shown in Fig. 13.

Fig. 16 is a circuit diagram of a conventional offset control circuit.

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DETAILED DESCRIPTION OF THE INVENTION

Hereinbelow, preferred embodiments of the present invention are described with reference to the appended drawings.

First Embodiment

Fig. 1 shows the entire configuration of a DVD signal reproduction processing system including the offset control circuit of the present invention.

In the DVD signal reproduction processing system (signal processing device) shown in the figure, numeral 40 denotes a DVD or CD (hereinafter, collectively called DVD), 41 denotes an optical pick-up for retrieving signals from the DVD, which is driven by a laser driver 42. This laser driver 42 is controlled by a laser controller 43. Numeral 44 denotes a disc motor for rotatively driving the DVD 40, which is driven by a motor driver 45.

Further, numeral 50 denotes a front-end, 60 denotes a back-end and 70 denotes a system controller, which are mounted on the same chip and integrated into one chip. Briefly, the front-end 50 performs data extraction processing including the readout, demodulation and error correction of data from the DVD 40, while performing a servo control and a laser control by outputting control signals to the laser controller 43 and the motor driver 45. On the other hand, the back-end 60 converts the reproduction signals of the DVD 40 that are sent from the front-end 50 into image signals and audio signals. Further, the system controller 70 coordinates a series of the processings performed by the front-end 50 and those performed by the back-end 60.

The front-end 50 includes, as its main portions, an analog front end 51 for performing such processing as the noise removal of the signals read out from the DVD 40 by the optical pick-up 41, and a digital PRML read channel 52. As described below, the analog front end 51 includes an offset control circuit 51c (see Fig. 2) of the present invention. This analog front end 51 calculates a servo focus error signal and a tracking error signal, and outputs these signals to a servo DSP 53. This servo DSP 53 controls the motor driver 45 such that the optical pick-up 41 accurately traces the recording data on the DVD 40, and controls the laser controller 43 so as to perform a laser power control.

The PRML read channel 52 performs, in cooperation with the analog front end 51,

a PR (Partial Response) processing of reproducing the original waveform by utilizing the property of the reproduction signals of being subjected to intersymbol interferences, and reads out the data with the highest probability from the reproduction signals based on the characteristics of the recording signals of the DVD 40. The data extracted from the PRML 5 read channel 52 is output to a formatter FMT. An ECC 54 performs Reed-Solomon error correction (error-correcting code) of the above-described extracted data. The data for which the modulation and the error correction have been completed is output to the back-end 60, via an AUDIO/VISUAL interface I/F. The above-described processes are controlled by a 32-bit CPU 55.

10 On the other hand, the back-end 60 includes an IO processor 61, a pixel control processor 62 and an AV decode processor 63. AUDIO/VISUAL data input from the front-end 50 via a stream interface 64 is subjected to a stream analysis with the IO processor 61, pixel processing with the pixel control processor 62 and decode processing with the AV decode processor 63, and is then output as audio/video data, via an AV interface 65.

15 In Fig. 1, an SDRAM 80 is provided outside the chip, and is shared by the front-end 50 and the back-end 60. Access to the SDRAM 80 is coordinated by an SDRAM interface 66 included in the back-end 60. When the front-end 50 accesses the SDRAM 80, it accesses the SDRAM interface 66, via a UMAC 56 included in the front-end 50.

20 Fig. 2 shows the internal configurations of the analog front end 51 and the PRML read channel 52.

In the figure, the analog front end 51 includes analog buffers 51a, a VGA circuit 51b, the offset control circuit 51c of the present invention, a 5th-order Gm-C filter 51d, two DACs (Digital Analog Converters) 51e, a wobble detector 51f and a servo pre-processing circuit 51g. On the other hand, the PRML read channel 52 includes a 7-bit ADC (Analog 25 Digital Converters) 52a, a 7-tap FIR (adaptive equalization) filter 52b, a Viterbi decoder 52c, an LMS 52d, a digital controller 52e and a PLL 52f. The above-described PR processing is performed with the 5th-order Gm-C filter 51d of the analog front end 51 and the FIR filter

52b of the PRML read channel **52**. The PRML read channel **52** demodulates the data quantized with the ADC **52a** to detect peaks and bottoms, and performs the amplitude control of the RF signals and the offset control in the offset control circuit **51c** based on the results of the modulation. This offset control is performed through an 8-bit digital control.

5 Next, the offset control circuit **51c** provided in the analog front end **51** is specifically described.

Fig. 3 is a block diagram showing an example of the configuration of the offset control circuit according to the first embodiment of the present invention.

10 In Fig. 3, an offset control circuit **1** includes a voltage/current converting circuit **10**, an offset adjusting current-generating circuit **11** connected to the two output terminals of the voltage/current converting circuit **10**, and a current/voltage converting circuit **12** connected to the two output terminals of the voltage/current converting circuit **10**.

15 The voltage/current converting circuit **10** includes a pair of differential voltage input terminals **109** and **110**, a control terminal **111** and a pair of differential current output terminals **105** and **106**. Differential input voltages **VIN+** and **VIN-** are input to the pair of differential voltage input terminals **109** and **110**, respectively, and controlled by the control signal input to the control terminal **111**, and differential output currents **I+** and **I-** are generated that are proportional to the differential input voltages **VIN+** and **VIN-**, respectively. The generated differential output currents **I+** and **I-** are output from the pair 20 of differential current output terminals **105** and **106**, respectively.

When the conversion coefficient of this voltage/current converting circuit **10** is **Gm**, the following relational expressions hold between the differential input voltages **VIN+** and **VIN**, and the differential output currents **I+** and **I-**:

$$I+ = Gm \times VIN+ \quad (\text{Equation 1})$$

25 $I- = Gm \times VIN- \quad (\text{Equation 2})$

The offset adjusting current-generating circuit **11** includes a pair of offset adjusting current-output terminals **101** and **102**, and a pair of offset adjusting current-control terminals

103 and **104**, is controlled by the control signal input to the offset adjusting current-control terminals **103** and **104**, and generates offset adjusting currents **I_{ofs}+** and **I_{ofs}-**. The generated offset adjusting currents **I_{ofs}+** and **I_{ofs}-** are output from the pair of offset adjusting current-output terminals **101** and **102**, respectively.

5 The current/voltage converting circuit 12 includes a pair of differential terminals
107 and 108, and an input/output current control terminal 112, and is configured such that a
current (differential input/output current) Ir that is proportional to the potential difference
between the pair of differential terminals 107 and 108 flows through it. The differential
terminal 107 of the current/voltage converting circuit 12 is connected to the differential
10 current output terminal 105 of the voltage/current converting circuit 10 and the offset
adjusting current-output terminal 101 of the offset adjusting current-generating circuit 11.
Similarly, the differential terminal 108 of the current/voltage converting circuit 12 is
connected to the differential current output terminal 106 of the voltage/current converting
circuit 10 and the offset adjusting current-output terminal 102 of the offset adjusting current-
15 generating circuit 11. The pair of differential terminals 107 and 108 are connected to a pair
of differential voltage output terminals 115 and 116, respectively, from which differential
output voltage signals VO_- and VO_+ are output, respectively.

When the differential input/output current flowing through the current/voltage converting circuit 12 is I_r and the direction of the current flowing from the differential terminal 108 towards the differential terminal 107 is positive in the offset control circuit 1 of this embodiment having the above-described configuration, the following expression holds for the differential terminal 107:

$$I_t = I_r + I_{ofs} + \dots \quad (Equation \ 3)$$

and the following expression holds for the differential terminal 108:

$$25 \quad I_- = -I_r + I_{ofs} \quad (\text{Equation 4})$$

From the above Equations 3 and 4, the differential input/output current I_r flowing between the differential terminals 107 and 108 of the current/voltage converting circuit 12 is

given as:

$$Ir = (1/2) \times \{(I_+ - I_-) + (I_{ofs+} - I_{ofs-})\} \quad (\text{Equation 5})$$

$$= (1/2) \times \{(I_+ + I_{ofs+}) - (I_- + I_{ofs-})\} \quad (\text{Equation 6})$$

From the above Equations 1, 2 and 5, the differential input/output current **Ir** is given as:

5 $Ir = (1/2) \times G_m (V_{IN+} - V_{IN-})$
+ $(1/2) \times (I_{ofs+} - I_{ofs-}) \quad (\text{Equation 7})$

Accordingly, when the conversion efficient of the current/voltage converting circuit **12** is **R**, the differential output voltage ($V_{O+} - V_{O-}$) output from the differential voltage output terminals **116** and **115** is given as:

10 $V_{O+} - V_{O-} = Ir \times R$
= $\{(1/2) \times G_m (V_{IN+} - V_{IN-})$
+ $(1/2) \times (I_{ofs+} - I_{ofs-})\} \times R \quad (\text{Equation 9})$

Next, let us consider a case where the differential input voltage signals **VIN+** and **VIN-** that are input from the differential voltage input terminals **109** and **110**, respectively, contain an offset voltage. When the offset voltage of each of the differential input voltage **VIN+** and **VIN-** is **Voff**, the differential output currents **I+** and **I-** output from the voltage/current converting circuit **10** are given as:

$$I_+ = G_m \times (V_{IN+} + V_{off}) \quad (\text{Equation 10})$$

$$I_- = G_m \times (V_{IN-} - V_{off}) \quad (\text{Equation 11})$$

20 Accordingly, from the above Equations (6), (10) and (11), the differential input/output current **Ir** flowing through the current/voltage converting circuit **12** in the offset control circuit **1** is given as:

$$Ir = (1/2) \times \{(G_m \times (V_{IN+} + V_{off}) + I_{ofs+})$$

- $G_m \times (V_{IN-} - V_{off}) + I_{ofs-}\} \quad (\text{Equation 12})$

25 From this, the differential output voltage ($V_{O+} - V_{O-}$) is given as:

$$V_{O+} - V_{O-} = (1/2) \times R \times G_m \times (V_{IN+} - V_{IN-})$$

+ $(1/2) \times R \times \{(G_m \times V_{off} + I_{ofs+})$

$$- (- G_m \times V_{off} + I_{ofs-}) \}$$

(Equation 13)

From the above Equation 13, it can be seen that in the differential output voltages **VO+** and **VO-** of the offset control circuit **1**, the offset current ($G_m \times V_{off}$) of the differential input voltages **VIN+** and **VIN-** is adjusted with the offset adjusting currents **Iofs+** and **Iofs-**.

As described above, this embodiment is based on the processing of differential signals, so that it does not require the operational amplifier **201** for the addition of the input voltage and the offset voltage, unlike the conventional example. Moreover, since the addition of the offset voltage to the input voltage is achieved by a simple current addition based on Kirchhoff's law after converting the input voltage and the offset voltage into currents, it is possible to adjust the offset voltage at very high speed.

Additionally, in a conventional offset addition method using the operational amplifier **201**, it is necessary to set the band of the operational amplifier **201** to about one or two orders higher than the band of the input signals, causing problems such as the increase of the circuit scale and power consumption, and the decrease of the processing speed limit. However, according to the first embodiment, it is possible to reduce the circuit scale and to perform the offset addition processing at higher speed, by a simple current addition based on Kirchhoff's law.

Furthermore, the offset control circuit **1** according to this embodiment is based on the processing of differential signals, so that it has a strong noise resistance and signal distortion hardly occurs. Although it is also possible to perform the processing of differential signals with the conventional offset control circuit **200** by providing two offset control circuits **200**, this requires twice the circuit scale and power consumption. In contrast to this, it is possible to perform an offset adjusting process using differential signals with the offset control circuit **1** according to this embodiment, by using a reduced circuit scale.

Although the front-end 50 including the offset control circuit 1, the back-end 60 and the system controller 70 are integrated into a single chip in this embodiment, it is of course also possible to integrate only the front-end 50 including the offset control circuit 1 into a single chip.

5 In addition, although the offset control circuit 1 provided in a DVD signal reproduction processing system is described in this embodiment, the present invention is not limited thereto and can be similarly used as the offset control circuits provided in systems other than DVD signal reproduction processing systems. In that case, the offset control circuit and a processing circuit for performing the predetermined processing for the 10 differential output voltages in which the offset voltage is adjusted with the offset control circuit may be integrated into a single chip.

Second Embodiment

15 The second embodiment describes a case where an offset control circuit 2 is realized by using a voltage/current converting circuit 10A as one specific example of the voltage/current converting circuit 10.

Fig. 4 is a circuit diagram showing one specific example of the voltage/current converting circuit 10 shown in Fig. 3.

20 In Fig. 4, the voltage/current converting circuit 10A includes a pair of bias current sources 301 and 302, a pair of first N-type transistors M3 and M4 that are connected to the bias current sources 301 and 302, respectively, and a pair of second N-type transistors M1 and M2 that are connected to the first N-type transistors M3 and M4, respectively.

25 The bias current sources 301 and 302 are connected to the differential current output terminals 105 and 106, respectively, so that a bias current Ib flows through the differential current output terminals 105 and 106.

The gates of the first transistors M3 and M4 are both connected to the control terminal 111, and a control voltage Vbias is input to these gates. The drains of the first

transistors **M3** and **M4** are connected to the differential current output terminals **105** and **106**, respectively, and the differential currents **I+** and **I-** are output from the differential current output terminals **105** and **106**, respectively.

The gates of the second N-type transistors **M1** and **M2** are connected to the differential voltage input terminals **109** and **110**, respectively, and the differential input voltage signals **VIN+** and **VIN-** are input to the gates of the differential voltage input terminals **109** and **110**, respectively. The drains of the second N-type transistors **M1** and **M2** are connected to the sources of the first transistors **M3** and **M4**, respectively, and their sources are grounded.

With the above-described configuration, the first N-type transistors **M3** and **M4** each operate as a source follower circuit in the voltage/current converting circuit **10A**, and the control voltage **Vbias** is input to the gates of the first transistors **M3** and **M4**, and a voltage that has been decreased by about the threshold voltage **Vth** is output from the sources of the first N-type transistors **M3** and **M4**. Consequently, the drain voltages of the second N-type transistors **M1** and **M2** are maintained constant, and the drain-source voltages **Vds** of the second N-type transistors **M1** and **M2** are maintained substantially constant.

The second N-type transistors **M1** and **M2** are each biased so as to operate in their unsaturated region. The drain currents **IDS1** and **IDS2** flowing through the second N-type transistors **M1** and **M2** at this time are given as:

$$IDS1 = \beta \times (VIN+ - Vth - Vds/2) \times Vds \quad (\text{Equation 14})$$

$$IDS2 = \beta \times (VIN- - Vth - Vds/2) \times Vds \quad (\text{Equation 15})$$

where β is the transconductance of the second transistors **M1** and **M2**, Vds is the drain-source voltage of the second N-type transistors **M1** and **M2**.

Here, in the voltage/current converting circuit **10A** of the second embodiment, the differential output current ($I+ - I-$) is equal to $IDS1 - IDS2$, and this differential output current flows into the current/voltage converting circuit **12**.

This results in the following equation:

$$\begin{aligned} I_+ - I_- &= IDS_1 - IDS_2 \\ &= \beta \times (VIN_+ - VIN_-) \times V_{ds} \end{aligned} \quad (\text{Equation 16})$$

From the above Equation 16, it can be seen that the differential output current $I_+ - I_-$

5 is proportional to the differential input voltage $VIN_+ - VIN_-$, and the proportional coefficient (conversion efficient) G_m is $\beta \times V_{ds}$.

As described above, the voltage/current converting circuit **10A** of the second embodiment operates as a differential voltage/current converting circuit. Therefore, by using this as the voltage/current converting circuit **10** shown in Fig. 3, it is possible to 10 realize the offset control circuit **2** of the second embodiment. This voltage/current converting circuit **10A** can reduce the distortion of signals by biasing the second N-type transistors **M1** and **M2** such that they operate in the unsaturated region. Using this voltage/current converting circuit **10A** to configure the offset control circuit **2** can prevent 15 the deterioration of the distortion characteristics. It should be noted that when the voltage/current converting circuit **10** is configured as in Fig. 4, the effect of achieving high-speed operation and size reduction in the offset control circuit **1** described in the above first embodiment will not be lost in any way.

In addition, with the voltage/current converting circuit **10A** of the second embodiment, it is possible to adjust the conversion coefficient G_m in the above Equation 13 20 by adjusting the control voltage **Vbias**. This means that it is possible to control the input/output voltage ratio, i.e., $(1/2) \times R \times G_m$, which is the coefficient of the differential input voltages **VIN+** and **VIN-**, in the above Equation 13. Accordingly, the offset control circuit **2** of the second embodiment not only has the offset adjusting function, but also can serve as a variable amplifier for changing the amplification factor of signals.

25 Furthermore, with the voltage/current converting circuit **10A** of the second embodiment, it is possible to fix the drain voltages of the second N-type transistors **M1** and **M2** more accurately. For example, by using an op-amp (operational amplifier), it is

possible to control the gate voltages of the first N-type transistors **M3** and **M4** such that the drain voltages of the second N-type transistors **M1** and **M2** are constant. Since the op-amp used in this case does not necessarily have to be highly accurate, it is sufficient that the band of the op-amp is about ten times the signal band. When the op-amp for controlling the gate voltages of the first N-type transistors **M3** and **M4** is provided in this manner, the effect of achieving high-speed operation and size reduction in the offset control circuit 1 described in the above first embodiment will not be lost in any way.

Third Embodiment

10 The third embodiment describes a case where signal distortion is further reduced in the offset control circuit 2 of the second embodiment.

Fig. 5 is a circuit diagram showing an example of the configuration of the offset control circuit according to the third embodiment of the present invention.

15 In Fig. 5, an offset control circuit 3 is realized by connecting the offset adjusting current-output terminals **101** and **102** of the offset adjusting current-generating circuit **11** to the drains of the second N-type transistors **M1** and **M2**, respectively, instead of the drains of the first N-type transistors **M3** and **M4**, of the voltage/current converting circuit **10A** in the offset control circuit 2 of the second embodiment. Consequently, the signal distortion in the offset control circuit 2 of the second embodiment is further reduced.

20 The operation of the offset control circuit 3 according to the third embodiment is described in comparison with those of the offset control circuits 1 and 2 of the above-described first and second embodiments, for a case where the differential input voltage signals **VIN+** and **VIN-** contain an offset voltage and the offset control circuit is operated so as to eliminate the offset voltage using the above-described configuration.

25 In the offset control circuits 1 and 2 of the first and second embodiments, although the second N-type transistors **M1** and **M2** and the first N-type transistors **M3** and **M4** are symmetrical circuits, an offset voltage is superimposed between the differential input

voltage signals V_{IN+} and V_{IN-} . Accordingly, different bias currents flow through these circuits. Such a current asymmetry is cancelled by adding the offset adjusting currents I_{ofs+} and I_{ofs-} that cancel the offset voltage (offset components) from the offset adjusting current-generating circuit **11** at the drains of the first N-type transistors **M3** and **M4**.

5 However, signal distortion is likely to occur, because the second N-type transistors **M1** and **M2** and the first N-type transistors **M3** and **M4** operate in an asymmetric state.

On the other hand, in the offset control circuit **3** of the third embodiment, the offset adjusting currents I_{ofs+} and I_{ofs-} from the offset adjusting current-generating circuit **11** are added to the differential output currents I_+ and I_- at the drains of the second N-type 10 transistors **M1** and **M2**, so that the current asymmetry is eliminated at this instant and the first N-type transistors **M3** and **M4** operate as symmetrical differential circuits also for bias currents I_+' and I_-' . Consequently, the offset control circuit **3** of the third embodiment can reduce signal distortion occurring in the first N-type transistors **M3** and **M4** to a lower level than the offset control circuits **1** and **2** of the first and second embodiments.

15 Furthermore, although the second N-type transistors **M1** and **M2** operate in an asymmetric state in the offset control circuit **3** of the third embodiment, they operate in the unsaturated region, so that even when their bias currents are different, the voltage/current characteristics are substantially the same as long as the source-drain voltages V_{ds} are the same. Accordingly, signal distortion occurring in the offset control circuit **3** as a whole can 20 be reduced even further than in the first and second embodiments.

It should be noted that when the offset control circuit **3** is configured as in Fig. 5, the effect of achieving high-speed operation and size reduction in the offset control circuit **1** described in the above first embodiment will not be lost in any way.

25 *Fourth Embodiment*

The fourth embodiment describes a case where an offset control circuit **4** that controls input/output gains through a resistance ratio by using a voltage/current converting

circuit **10C** as another specific example of the voltage/current converting circuit **10**.

Fig. 6 is a circuit diagram showing another specific example of the voltage/current converting circuit **10** shown in Fig. 3.

In Fig. 6, the voltage/current converting circuit **10C** includes a pair of bias current sources **301** and **302**, a pair of first N-type transistors **M7** and **M8** and a pair of second N-type transistors **M5** and **M6**. Two series circuits, one made up of the bias current source **301**, the first N-type transistor **M7** and the second N-type transistor **M5**, the other made up of the bias current source **302**, the first N-type transistor **M8** and the second N-type transistor **M6**, are provided in the voltage/current converting circuit **10C**. Further, a resistor **R3** is disposed between the point where the first N-type transistor **M7** and the second N-type transistor **M5** are connected and the point where the first N-type transistor **M8** and the second N-type transistor **M6** are connected.

The bias current sources **301** and **302** are connected to the differential current output terminals **105** and **106**, respectively, so that a bias current **Ib** flows through the differential current output terminals **105** and **106**.

The gates of the first N-type transistors **M7** and **M8** are connected to the differential voltage input terminals **109** and **110**, respectively, and the differential input voltages **VIN+** and **VIN-** are input to the differential voltage input terminals **109** and **110**, respectively. Further, the drains of the first N-type transistors **M7** and **M8** are connected to the differential current output terminals **105** and **106**, respectively, and the resistor **R3** is connected between the sources of the first N-type transistors **M7** and **M8**.

The gates of the second N-type transistors **M5** and **M6** are both connected to the control terminal **111**, and a control voltage **Vbias** is input to that control terminal **111**. Further, the drains of the second N-type transistors **M5** and **M6** are connected to the sources of the first N-type transistors **M7** and **M8**, respectively, and their sources are grounded.

In the voltage/current converting circuit **10C** of the fourth embodiment having the above-described configuration, the first N-type transistors **M7** and **M8** each operate as a

source follower circuit. Based on the differential input voltage signal **VIN+** and **VIN-** respectively input to the gates of the first N-type transistors **M7** and **M8**, a voltage that has been decreased by about the threshold voltage **Vth** is output from the sources and applied across the resistor **R3**. Consequently, a potential difference (**VIN+** – **VIN-**) is generated in the resistor **R3**, and a current (**VIN+** – **VIN-**)/**R3** is generated according to Ohm's law.

Therefore, the current conversion efficient **Gm** in the voltage/current converting circuit **10C** of the fourth embodiment is approximately 1/**R3**, and the differential output current (**VIN+** – **VIN-**)/**R3** is output from the differential current output terminals **105** and **106**, via the first N-type transistors **M7** and **M8**. The second N-type transistors **M5** and **M6** each operate as a circuit for applying a bias current to the first N-type transistors **M7** and **M8**.

As described above, the voltage/current converting circuit **10C** of the fourth embodiment operates as a differential voltage/current converting circuit. By using this as the voltage/current converting circuit **10** shown in Fig. 3, it is possible to realize the offset control circuit 4. Since the current/voltage coefficient **Gm** of this voltage/current converting circuit **10** is approximately 1/**R3**, the input/output voltage ratio in the case of operating this the voltage/current converting circuit **10** as the offset control circuit 4, i.e., $(1/2) \times Gm \times R$, which is the conversion efficient of the differential input voltage signals **VIN+** and **VIN-**, in the above Equation 13 is $(1/2) \times (R/R3)$ and it can be seen that it depends on the ratio of the resistor **R** (conversion efficient) of the current/voltage converting circuit **12** to the resistor **R3** of the voltage/current converting circuit **10**. Therefore, the input/output gains of the offset control circuit 4 of the fourth embodiment can be controlled through a resistance ratio.

It should be noted that when the voltage/current converting circuit **10** is configured as in Fig. 6, the effect of achieving high-speed operation and size reduction in the offset control circuit 1 described in the above first embodiment will not be lost in any way.

Additionally, in the voltage/current converting circuit **10C** of the fourth

embodiment, it is possible to apply feedback by using an op-amp in such a manner that the source potentials of the first N-type transistors **M7** and **M8** are equal to the gate potentials of the first N-type transistors **M7** and **M8**. This makes it possible to further reduce signal distortion and increase the accuracy of the setting of input/output gains with a resistance 5 value. When the voltage/current converting circuit **10** is provided with an op-amp for controlling the gate potentials and the source potentials of the first N-type transistors **M7** and **M8** in this manner, the effect of achieving high-speed operation and size reduction in the offset control circuit **1** described in the above first embodiment will not be lost in any way.

10

Fifth Embodiment

The fifth embodiment describes a case where an offset control circuit **5** that can operate at very high speed is realized by using a voltage/current converting circuit **10D** as yet another specific example of the voltage/current converting circuit **10**.

15

Fig. 7 is a circuit diagram showing yet another specific example of the voltage/current converting circuit **10** shown in Fig. 3.

20

In Fig. 7, the voltage/current converting circuit **10D** includes a pair of bias current sources **301** and **302**, a pair of N-type transistors **M9** and **M10**. Two series circuits, one made up of the bias current source **301** and the N-type transistor **M9**, the other made up of the bias current source **302** and the N-type transistor **M10**, are provided in the voltage/current converting circuit **10D**.

The bias current sources **301** and **302** are connected to the differential current output terminals **105** and **106**, respectively, so that a bias current **Ib** flows through the differential current output terminals **105** and **106**.

25

The gates of the N-type transistors **M9** and **M10** are connected to the differential voltage input terminals **109** and **110**, respectively, and the differential input voltages **VIN+** and **VIN-** are input to the differential voltage input terminals **109** and **110**, respectively.

Further, the drains of the N-type transistors **M9** and **M10** are connected to the differential current output terminals **105** and **106**, respectively, and the sources of the N-type transistors **M9** and **M10** are grounded.

In the voltage/current converting circuit **10D** of the fifth embodiment having the 5 above-described configuration, the differential input voltage ($V_{IN+} - V_{IN-}$) input to the gates of the N-type transistors **M9** and **M10** is converted to a current in accordance with the voltage/current conversion characteristics of the N-type transistors **M9** and **M10**, and then output as the differential current ($I_+ - I_-$) from the differential current output terminals **105** and **106**.

10 As described above, the voltage/current converting circuit **10D** of the fifth embodiment operates as a differential voltage/current converting circuit. Accordingly, by using this as the voltage/current converting circuit **10** shown in Fig. 3, it is possible to realize the offset control circuit **5** of the fifth embodiment. This voltage/current converting circuit **10D** can operate at very high speed, since only the N-type transistors **M9** and **M10** 15 are present between the differential voltage input terminals **109** and **110** and the differential current output terminals **105** and **106**. Therefore, the offset control circuit **5** of the fifth embodiment can operate at very high speed. It should be noted that when the voltage/current converting circuit **10** shown in Fig. 3 is configured as in Fig. 7, the effect of achieving high-speed operation and size reduction in the offset control circuit **1** described in 20 the above first embodiment will not be lost in any way.

Sixth Embodiment

The sixth embodiment describes a case where an offset control circuit **6** is realized by using a current/voltage converting circuit **12A** as one specific example of the 25 current/voltage converting circuit **12**.

Fig. 8 is a circuit diagram showing one specific example of the current/voltage converting circuit **12** shown in Fig. 3.

In Fig. 8, a resistor **R4** is disposed between differential terminals **107** and **108** in the current/voltage converting circuit **12A**.

In the current/voltage converting circuit **12A** of the sixth embodiment having the above-described configuration, the resistor **R4** can generate a voltage across the two terminals (differential terminals) **107** and **108** that is proportional to a current (differential input/output current **Ir**) flowing through the resistor **R4**. Therefore, by using this as the current/voltage converting circuit **12** shown in Fig. 3, it is possible to realize the offset control circuit **6** of the sixth embodiment.

It should be noted that when the current/voltage converting circuit **12** shown in Fig. 10 3 (or Fig. 5) is configured as in Fig. 8, the effect of achieving high-speed operation and size reduction in the offset control circuits **1** and **3** described in the above first embodiment (or the above third embodiment) will not be lost in any way.

Seventh Embodiment

15 The seventh embodiment describes a case where an offset control circuit **7** is realized by using a current/voltage converting circuit **12B** as another specific example of the current/voltage converting circuit **12**.

Fig. 9 is a circuit diagram showing another specific example of the current/voltage converting circuit **12** shown in Fig. 3.

20 In Fig. 9, the current/voltage converting circuit **12B** includes a pair of differential terminals **107** and **108**, a pair of first N-type transistors **M13** and **M14** and a pair of second N-type transistors **M11** and **M12**.

The differential terminal **107**, the first N-type transistor **M13** and the second N-type transistor **M11** are connected in series, and also the differential terminal **108**, the first N-type transistor **M14** and the second N-type transistor **M12** are connected in series. The gates of the first N-type transistors **M13** and **M14** are both connected to an input/output current control terminal **112**, and a control voltage **Vbias2** is input to the input/output current

control terminal 112. The gates of the second N-type transistors **M11** and **M12** are connected to the differential terminals 107 and 108, respectively, and a voltage proportional to a differential input/output current **Ir** is applied to the differential terminals 107 and 108.

In the current/voltage converting circuit 12B of the seventh embodiment having the above-described configuration, the first N-type transistors **M13** and **M14** and the second N-type transistors **M11** and **M12** operate in the same manner as the first transistors **M3** and **M4** and the second transistors **M1** and **M2** of the voltage/current converting circuit 10B shown in Fig. 5, respectively. More specifically, the first N-type transistors **M13** and **M14** each operate as a source follower circuit, and, based on the control voltage **Vbias2** input to the gates of the first N-type transistors **M13** and **M14**, a voltage that has been decreased by about the threshold voltage **Vth** is output from the sources. Consequently, the drain voltages of the second N-type transistors **M11** and **M12** are maintained constant, and the drain-source voltages **Vds** of the second N-type transistors **M11** and **M12** are maintained substantially constant.

The second N-type transistors **M11** and **M12** are each biased so as to operate in the unsaturated region, and a current proportional to the voltages applied to the gates of the second N-type transistors **M11** and **M12** is input/output from the differential terminals 107 and 108.

Therefore, the current/voltage converting circuit 12 of the seventh embodiment operates in such a manner that the differential input/output current **Ir** proportional to the voltage applied across the differential terminals 107 and 108 is input/output from the differential terminals 107 and 108. In other words, it operates in such a manner that a voltage is generated across the differential terminals 107 and 108 that is proportional to the differential input/output current that is input/output to the differential terminals 107 and 108.

As described above, the current/voltage converting circuit 12B of the seventh embodiment operates as a differential current/voltage converting circuit. Therefore, by using this as the current/voltage converting circuit 12 shown in Fig. 3 (or Fig. 5), it is

possible to realize the offset control circuit 7. In the current/voltage converting circuit 12B of the seventh embodiment, it is possible to adjust the current/voltage conversion coefficient **R** in the above Equation 13 by adjusting the control voltage **Vbias2**. Accordingly, the offset control circuit 7 of the seventh embodiment not only has the offset adjustment function, but also can serve as a variable amplifier capable of changing the amplification factor of signals. It should be noted that when the current/voltage converting circuit 12 shown in Fig. 3 (or Fig. 5) is configured as in Fig. 9, the effect of achieving high-speed operation and size reduction in the offset control circuits 1 and 3 described in the above first embodiment (or the above third embodiment) will not be lost in any way.

10

Eighth Embodiment

The eighth embodiment describes a case where an offset control circuit 8 is realized by using a current/voltage converting circuit 12C as yet another specific example of the current/voltage converting circuit 12.

15 Fig. 10 is a circuit diagram showing yet another specific example of the current/voltage converting circuit 12 shown in Fig. 3.

In Fig. 10, as the current/voltage converting circuit 12C, a P-type transistor **M15** is disposed between differential terminals 107 and 108. The gate of this P-type transistor **M15** is connected to an input/output current control terminal 112, and a control voltage 20 **Vbias2** is input to the input/output current control terminal 112.

In the current/voltage converting circuit 12C of the eighth embodiment having the above-described configuration, the P-type transistor **M15** operates as a variable resistor whose resistance can be controlled in accordance with the control voltage **Vbias2** applied to the gate of the P-type transistor **M15**.

25 As described above, the current/voltage converting circuit 12C of the eighth embodiment operates as a differential current/voltage converting circuit. Therefore, by using this as the current/voltage converting circuit 12 shown in Fig. 3 (or Fig. 5), it is

possible to realize the offset control circuit **8** of the eighth embodiment. In the current/voltage converting circuit **12C** of the eighth embodiment, it is possible to adjust the current/voltage conversion coefficient **R** in the above Equation 13 by adjusting the control voltage **Vbias2**. Accordingly, the offset control circuit **8** of the eighth embodiment not only has the offset adjustment function, but also can serve as a variable amplifier capable of changing the amplification factor of signals. It should be noted that when the current/voltage converting circuit **12** shown in Fig. 3 (or Fig. 5) is configured as in Fig. 10, the effect of achieving high-speed operation and size reduction in the offset control circuits **1** and **3** described in the above first embodiment (or the above third embodiment) will not be lost in any way.

Ninth Embodiment

The ninth embodiment describes a case where an offset control circuit **9** is realized by using an offset adjusting current-generating circuit **11A** as one specific example of the offset adjusting current-generating circuit **11**.

Fig. 11 is a circuit diagram showing one specific example of the offset adjusting current generating circuit **11** shown in Fig. 3.

In Fig. 11, the offset adjusting current-generating circuit **11A** includes a bias current source **307**, a pair of P-type transistors **M16** and **M17** and a pair of offset adjusting current-output terminals **101** and **102**.

The bias current source **307** is connected to the sources of the P-type transistors **M16** and **M17** in such a manner that a bias current **Iofs** is divided into two branches so as to flow through the P-type transistors **M16** and **M17**.

The gates of the P-type transistors **M16** and **M17** are connected to offset adjusting current-control terminals **103** and **104**, respectively, and offset adjusting current-control voltages **Vofs+** and **Vofs-** are input to the offset adjusting current-control terminals **103** and **104**, respectively. The drains of the P-type transistors **M16** and **M17** are connected to the

offset adjusting current-output terminals **101** and **102**, respectively, and offset adjusting currents **Iofs+** and **Iofs-** flow through the offset adjusting current-output terminals **101** and **102**.

In the offset adjusting current-generating circuit **11A** of the ninth embodiment
5 having the above-described configuration, the amounts of the offset adjusting currents **Iofs+** and **Iofs-** are adjusted with the offset adjusting current-control voltages **Vofs+** and **Vofs-**, respectively.

Thus, by using the offset adjusting current-generating circuit **11A** as the offset
adjusting current-generating circuit **11** shown in Fig. 3 (or Fig. 5), it is possible to realize the
10 offset control circuit **9** of the ninth embodiment.

It should be noted that when the offset adjusting current-generating circuit **11**
shown in Fig. 3 (or Fig. 5) is configured as in Fig. 11, the effect of achieving high-speed
operation and size reduction in the offset control circuits **1** and **3** described in the above first
embodiment (or the above third embodiment) will not be lost in any way.

15 Additionally, it is also possible to configure an offset adjusting current-generating
circuit **11B** as shown in Fig. 12 by using a bias current source **308** and P-type transistors
M18 and **M19**, each having the opposite polarity as that of the bias current source **307** and
the P-type transistors **M16** and **M17** in the offset adjusting current-generating circuit **11A** of
the ninth embodiment. Also in this case, as described above, when the offset adjusting
20 current-generating circuit **11** shown in Fig. 3 (or Fig. 5) is configured as in Fig. 12, the effect
of achieving high-speed operation and size reduction in the offset control circuits **1** and **3**
described in the above first embodiment (or the above third embodiment) will not be lost in
any way.

25 *Tenth Embodiment*

The tenth embodiment describes a case where an offset control circuit **10** is realized
by using a digitally controllable offset adjusting current-generating circuit **13** that is different

from the offset adjusting current-generating circuit 11.

Fig. 13 is a circuit diagram showing an example of the configuration of an offset adjusting current-generating circuit that is different from the offset adjusting current-generating circuit 11 shown in Fig. 3.

5 In Fig. 13, the offset adjusting current-generating circuit 13 includes, in place of the offset adjusting current-control terminals 103 and 104 of the offset adjusting current-generating circuit 11 shown in Fig. 3 (or Fig. 5), input terminals (offset adjusting current-control terminals) 113-1 to 113-n to which one-bit register signals of an n-bit register signal (n is a natural number) are input, respectively. The offset adjusting currents I_{ofs+} and
10 I_{ofs-} can be controlled with high accuracy, in accordance with the state of the n-bit register signal input from the input terminals 113-1 to 113-n.

Fig. 14 is a circuit diagram showing one specific example of the offset adjusting current-generating circuit 13 shown in Fig. 13.

15 In Fig. 14, an offset adjusting current-generating circuit 13A includes n sub-offset adjusting current-generating portions 13-1 to 13-n. The sub-offset adjusting current-generating portions 13-1 to 13-n include, respectively, inverters 14-1 to 14-n, bias current sources 309-1 to 309-n and pairs of P-type transistors M20-1 to M20-n and M21-1 to M21-n.

20 The bias current source 309-1 is connected to the sources of the P-type transistors M20-1 and M21-1, and a bias current is divided into two branches so as to flow through the sources of the P-type transistors M20-1 and M21-1. Similarly, the bias current source 309-n (n is a natural number) is connected to the sources of the P-type transistors M20-n and M21-n, and a bias current is divided into two branches so as to flow through the sources of the P-type transistors M20-n and M21-n. The current values of the bias current sources 25 309-1 to 309-n are weighted to be $I_{ofs'}$, $2 \times I_{ofs'}$, ..., and $n \times I_{ofs'}$, respectively.

The gates of the P-type transistors M20-1 to M20-n are connected to the input terminals 113-1 to 113-n, respectively, and a one-bit register signal is input to the input

terminals **113-1** to **113-n**. Further, the input terminals **113-1** to **113-n** are connected to the gates of the P-type transistors **M21-1** to **M21-n**, respectively, via inverters **14-1** to **14-n**, respectively, and the inverted signal of the one-bit register signal (offset adjusting current control signal) is input to the gates of the P-type transistors **M21-1** to **M21-n**.

5 The drains of the P-type transistors **M20-1** to **M20-n** are connected to an offset adjusting current-output terminal **101**, and sub-offset adjusting currents **Iofs (1)+** to **Iofs (n)+** all flow through the offset adjusting current-output terminal **101**. The drains of the P-type transistors **M21-1** to **M21-n** are connected to an offset adjusting current-output terminal **102**, and the sub-offset adjusting currents **Iofs (1)-** to **Iofs (n)-** all flow through the 10 offset adjusting current-output terminal **102**. Consequently, the values of the offset adjusting current **Iofs+** is the sum of **Iofs (1)+**, **Iofs (2)+**, ... **Iofs (n)+**, and the value of the offset adjusting current **Iofs-** is the sum of **Iofs (1)-**, **Iofs (2)-**, ... **Iofs (n)-**.

15 In the offset adjusting current-generating circuit **13A** of the tenth embodiment having the above-described configuration, the register signal serving as the control signal for controlling the offset adjusting currents is input from the input terminals **113-1** to **113-n**. For example, when the register signal input to the input terminal **113-1** is at level **H**, a signal at level **H** is applied to the gate of the P-type transistor **M20-1** in the sub-offset adjusting current-generating circuit **13-1**. The register signal input to the input terminal **113-1** is inverted by the inverter **14-1** to level **L**, so that a signal at level **L** is applied to the gate of 20 the P-type transistor **M21-1**. Each of the P-type transistors **M20-1** and **M21-1** is in an ON state when a signal at level **L** is applied to their gates, so that the P-type transistor **M20-1** is in an OFF state and **Iofs (1)+** does not flow through it, whereas the P-type transistor **M21-1** is in an ON state and **Iofs (1)-** flows through it.

25 On the other hand, when the register signal input to the input terminal **113-1** is at level **L**, a signal at level **L** is applied to the gate of the P-type transistor **M20-1**. Further, the register signal input to the input terminal **113-1** is inverted by the inverter **14-1** to level **H**, so that a signal at level **H** is applied to the gate of the P-type transistor **M21-1**.

Accordingly, the P-type transistor **M20-1** is in an ON state and **Iofs (1)+** flows through it, whereas the P-type transistor **M21-1** is in an OFF state and **Iofs (1)-** does not flow through it.

As described above, in accordance with the state of the register signal input to the input terminal **113-1**, either **Iofs (1)+** or **Iofs (1)-** flows through the sub-offset adjusting 5 current-generating circuit **13-1**. The currents **Iofs (1)+** and **Iofs (1)-** are equal to the bias current **Iofs-'**, when they flow through the sub-offset adjusting current-generating circuit **13-1**.

Similarly, in accordance with the state of the register signals input from the input terminals **113-2** to **113-n**, the P-type transistors **M20-2** to **M20-n** are turned on and off in 10 order to set **Iofs (2)+**, ... **Iofs (n)+**, and the P-type transistors **M21-2** to **M21-n** are turned on and off in order to set **Iofs (2)-**, ... **Iofs (n)-**.

At this time, when either one of the currents of the sets of currents (**Iofs (1)+** and **Iofs (1)-**), (**Iofs (2)+** and **Iofs (2)-**), ... and (**Iofs (n)+** and **Iofs (n)-**) flows, the other one does not flow.

15 Each of the register signal is made up of n bits, and there are n possible register signals for the case where all of the register signals are at level **L** (**LL**, ... **L**) to the case where all of the register signals are at level **H** (**HH**, ... **H**).

When all of the register signals are at level **L**, all of the P-type transistors **M20-1** to **M20-n** are in an ON state, the offset adjusting current **Iofs+** flows and the amount of the 20 offset adjusting current **Iofs+** is at the maximum. At this time, all of the P-type transistors **M21-1** to **M21-n** are in an OFF state, and the offset adjusting current **Iofs-** does not flow.

When all of the register signals are at level **L**, all of the P-type transistors **M21-1** to **M21-n** are in an ON state, the offset adjusting current **Iofs-** flows and the amount of the offset adjusting current **Iofs-** is at the maximum. At this time, all of the P-type transistors 25 **M20-1** to **M20-n** are in an OFF state, and the offset adjusting current **Iofs+** does not flow.

When not all of the register signals are at level **L** or level **H**, a number of P-type transistors **M20-1** to **M20-n** is turned on that is equal to the number of the register signals at

level **L** among the n-bit register signals, and accordingly **Iofs (1)+**, **Iofs (2)+**, ... **Iofs (n)+** flows, and the sum of these currents is the offset adjusting current **Iofs+**. Further, a number of P-type transistors **M21-1** to **M21-n** is turned on that is equal to the number of the register signals at level **H** among the n-bit register signals, and accordingly **Iofs (1)-**, **Iofs (2)-**, ... **Iofs (n)-** flows, and the sum of these currents is the offset adjusting current **Iofs-**.

As described above, the offset adjusting current-generating circuit **13A** of the tenth embodiment operates as a DA converter that outputs differential currents, making it possible to adjust the offset adjusting currents **Iofs+** and **Iofs-** with n-bit register signals at an accuracy of $Iofs+/n$ or $Iofs-/n$. Moreover, according to the tenth embodiment, the offset adjusting current-generating circuit **13** is configured as an n-bit DA converter, so that it is possible to control the amount of offset adjustment with a digital circuit, thereby easily realizing a further variety of offset adjustment.

Further, it is possible to improve the accuracy of the current adjustment by increasing the number n of the register signals in the offset adjusting current-generating circuit **13A** shown in Fig. 14. It should be noted that when the offset adjusting current-generating circuit **13** shown in Fig. 13 is configured as in Fig. 14, the effect of achieving high-speed operation and size reduction in the offset control circuits **1** and **3** described in the above first embodiment (or the third embodiment) will not be lost in any way.

Additionally, it is also possible to configure an offset adjusting current-generating circuit **13B** as shown in Fig. 15 by using bias current sources **310-1** to **310-n** and P-type transistors **M22-1** to **M22-** and **M23-1** to **M23-n**, each of which has opposite polarity as that of the bias current sources **309-1** to **309-n** and the P-type transistors **M20-1** to **M20-** and **M21-1** to **M21-n**, and providing inverters **15-1** to **15-n**, which are connected in the direction opposite from that of the inverters **14-1** to **14-n**, in the offset adjusting current-generating circuit **13A** of the tenth embodiment. When the offset adjusting current-generating circuit **13** shown in Fig. 13 is configured as in Fig. 15, the effect of achieving high-speed operation and size reduction in the offset control circuits **1** and **3** described in the

above first embodiment (or the above third embodiment) will not be lost in any way.

The invention may be embodied in other forms without departing from the spirit or essential characteristics thereof. The embodiments disclosed in this application are to be considered in all respects as illustrative and not limiting. The scope of the invention is indicated by the appended claims rather than by the foregoing description, and all changes which come within the meaning and range of equivalency of the claims are intended to be embraced therein.